



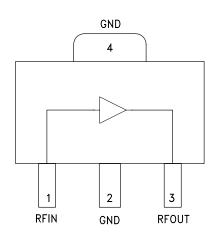
## InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

### Typical Applications

The HMC789ST89E is ideal for:

- Cellular/4G
- Fixed Wireless & WLAN
- CATV, Cable Modem & DBS
- Microwave Radio & Test Equipment
- IF & RF Applications

### **Functional Diagram**



#### **Features**

High Output IP3: +42 dBm High Output P1dB: +25 dBm

High Gain: 18 dB Single Supply: +5V

45% PAE @ +25 dBm Pout

Industry Standard SOT89 Package

### **General Description**

The HMC789ST89E is a high linearity GaAs InGaP HBT gain block MMIC operating from 0.7 to 2.8 GHz and packaged in an industry standard SOT89 package. Utilizing a minimum number of external components and a single +5V supply, the amplifier output IP3 can be optimized to +45 dBm. The high output IP3 and high gain make the HMC789ST89E ideal for use in PA driver & pre-driver applications in Cellular/4G and Fixed Wireless.

### Electrical Specifications, $T_A = +25^{\circ}\text{C}$ , $Vs = +5V^{[1]}$

| Parameter                               | Min.      | Тур. | Max.        | Min. | Тур.        | Max. | Min. | Тур. | Max. | Units   |
|---|-----------|------|-------------|------|-------------|------|------|------|------|---------|
| Frequency Range                         | 810 - 960 |      | 1710 - 1990 |      | 2420 - 2700 |      | MHz  |      |      |         |
| Gain                                    | 17        | 18   |             | 12   | 13.5        |      | 10   | 11   |      | dB      |
| Gain Variation Over Temperature         |           | 0.01 |             |      | 0.01        |      |      | 0.01 |      | dB / °C |
| Input Return Loss                       |           | 12   |             |      | 12          |      |      | 10   |      | dB      |
| Output Return Loss                      |           | 20   |             |      | 15          |      |      | 10   |      | dB      |
| Output Power for 1dB Compression (P1dB) | 21        | 23.5 |             | 23   | 25          |      | 22   | 24   |      | dBm     |
| Saturated Output Power (Psat)           |           | 25.5 |             |      | 27          |      |      | 26   |      | dBm     |
| Output Third Order Intercept (IP3) [2]  |           | 42   |             |      | 42          |      |      | 42   |      | dBm     |
| Noise Figure                            |           | 3.8  |             |      | 3.8         |      |      | 3.8  |      | dB      |
| Supply Current (Icq)                    |           | 125  | 150         |      | 125         | 150  |      | 125  | 150  | mA      |

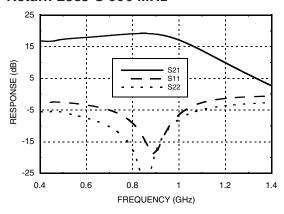
<sup>[1]</sup> Specifications and data reflect HMC789ST89E measured using the respective application circuits for each designated frequency band found herein. Contact the HMC Applications Group for assistance in optimizing performance for your application.

<sup>[2]</sup> Two-tone output power of +10 dBm per tone, 1 MHz spacing.

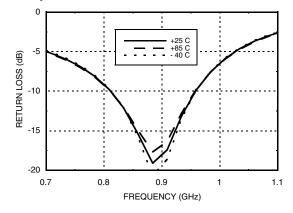




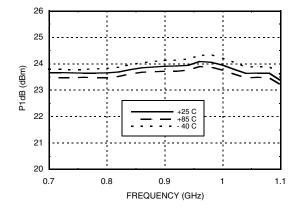
### Broadband Gain & Return Loss @ 900 MHz



### Input Return Loss vs. Temperature @ 900 MHz

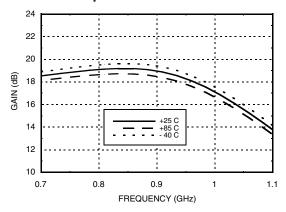


### P1dB vs. Temperature @ 900 MHz

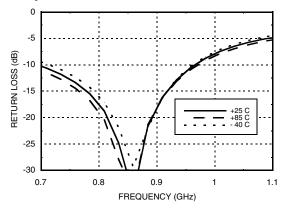


## InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

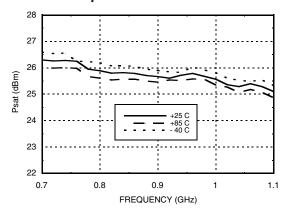
### Gain vs. Temperature @ 900 MHz



### Output Return Loss vs. Temperature @ 900 MHz



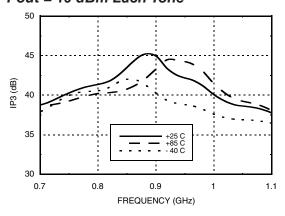
### Psat vs. Temperature @ 900 MHz



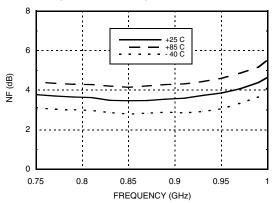




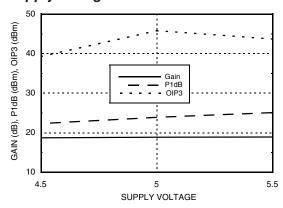
### Output IP3 vs. Temperature @ 900 MHz Pout = 10 dBm Each Tone



### Noise Figure vs. Temperature @ 900 MHz

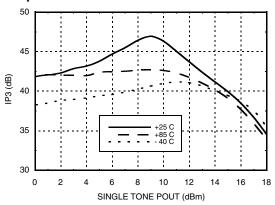


### Gain, Power & IP3 vs. Supply Voltage @ 900 MHz

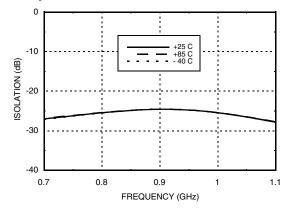


## InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

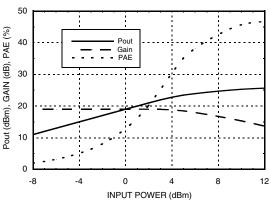
### Output IP3 vs. Output Power @ 900 MHz



### Reverse Isolation vs. Temperature @ 900 MHz



### Power Compression @ 900 MHz

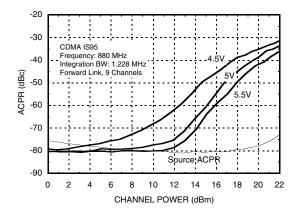




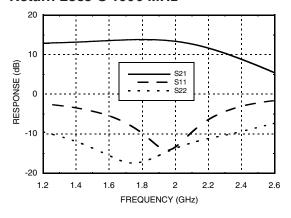


## InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

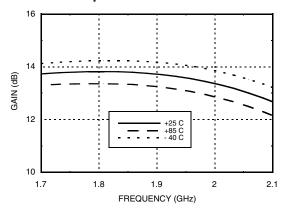
## ACPR vs. Supply Voltage @ 880 MHz CDMA IS95, 9 Channels Forward



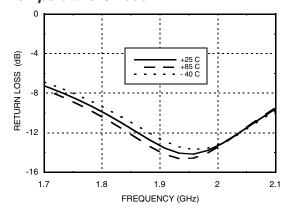
### Broadband Gain & Return Loss @ 1900 MHz



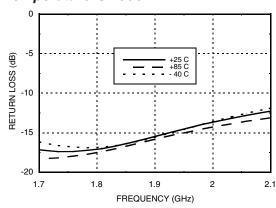
### Gain vs. Temperature @ 1900 MHz



### Input Return Loss vs. Temperature @ 1900 MHz



### Output Return Loss vs. Temperature @ 1900 MHz

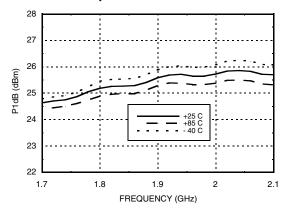




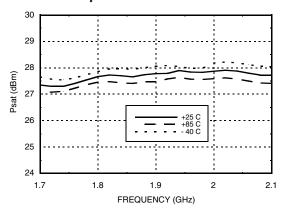


# InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

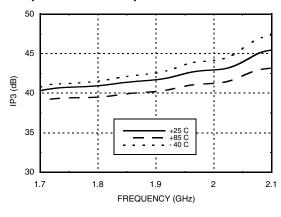
### P1dB vs. Temperature @ 1900 MHz



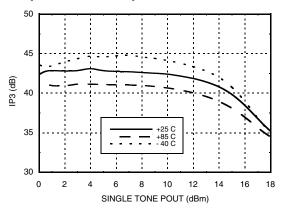
### Psat vs. Temperature @ 1900 MHz



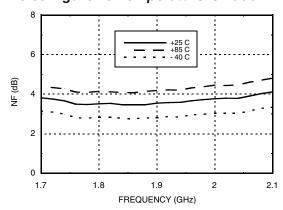
### Output IP3 vs. Temperature @ 1900 MHz



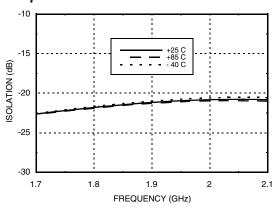
Output IP3 vs. Output Power @ 1900 MHz



### Noise Figure vs. Temperature @ 1900 MHz



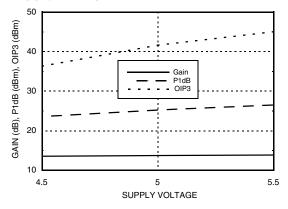
### Reverse Isolation vs. Temperature @ 1900 MHz



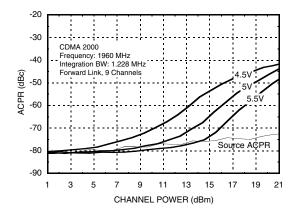




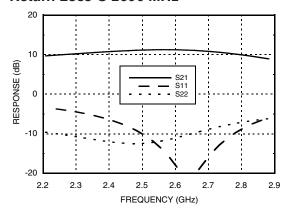
### Gain, Power & IP3 vs. Supply Voltage @ 1900 MHz



## ACPR vs. Supply Voltage @ 1960 MHz CDMA 2000, 9 Channels Forward

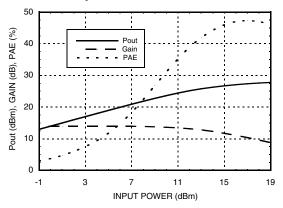


### Broadband Gain & Return Loss @ 2600 MHz

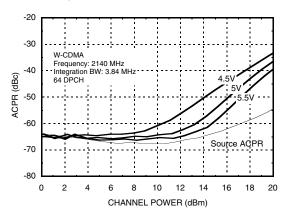


## InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

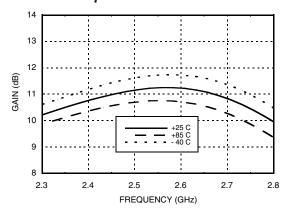
### Power Compression @ 1900 MHz



## ACPR vs. Supply Voltage @ 2140 MHz W-CDMA, 64 DPCH



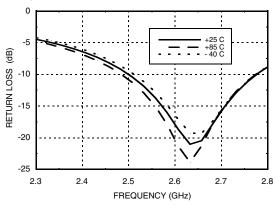
### Gain vs. Temperature @ 2600 MHz



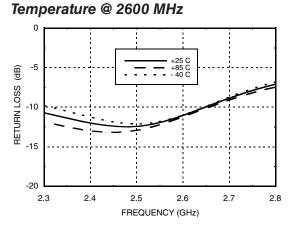




### Input Return Loss vs. Temperature @ 2600 MHz



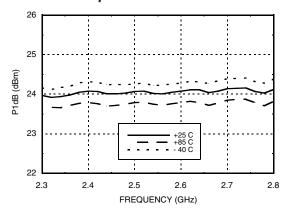
## Output Return Loss vs.



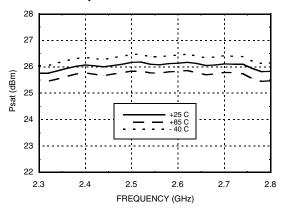
InGaP HBT GAIN BLOCK MMIC

AMPLIFIER, 0.7 -2.8 GHz

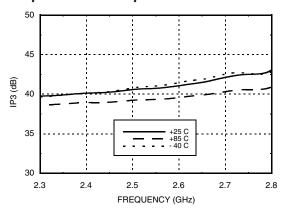
### P1dB vs. Temperature @ 2600 MHz



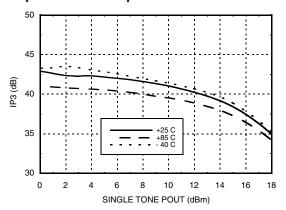
Psat vs. Temperature @ 2600 MHz



### Output IP3 vs. Temperature @ 2600 MHz



### Output IP3 vs. Output Power @ 2600 MHz

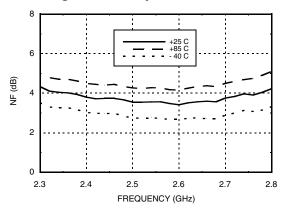




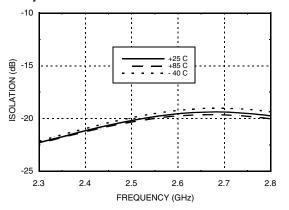


## InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

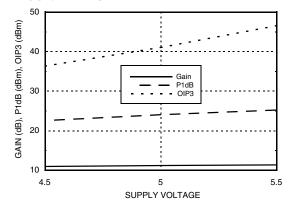
### Noise Figure vs. Temperature @ 2600 MHz



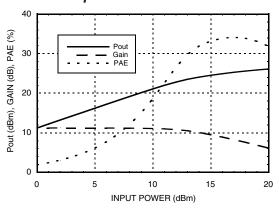
### Reverse Isolation vs. Temperature @ 2600 MHz



### Gain, Power & IP3 vs. Supply Voltage @ 2600 MHz



### Power Compression @ 2600 MHz







## InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

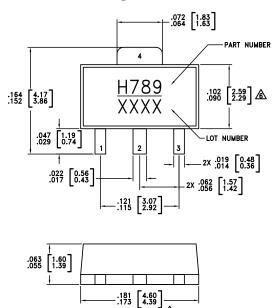
### **Absolute Maximum Ratings**

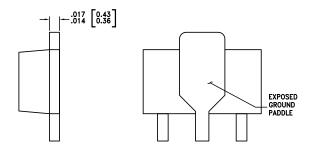
| Collector Bias Voltage (Vcc)                                    | +6.0 V         |
|---|----------------|
| RF Input Power (RFIN)(Vs +5Vdc)                                 | +18 dBm        |
| Junction Temperature  | 150 °C         |
| Continuous Pdiss (T = 85 °C)<br>(derate 13.0 mW/°C above 85 °C) | 0.85 W         |
| Thermal Resistance (junction to ground paddle)                  | 77 °C/W        |
| Storage Temperature   | -65 to +150 °C |
| Operating Temperature   | -40 to +85 °C  |



### ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

### **Outline Drawing**





#### NOTES:

- 1. PACKAGE BODY MATERIAL:
- MOLDING COMPOUND MP-180S OR EQUIVALENT.
- 2. LEAD MATERIAL: Cu w/ Ag SPOT PLATING.
- 3. LEAD PLATING: 100% MATTE TIN.
- 4. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 7. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

### Package Information

| Part Number | Package Body Material                              | Lead Finish   | MSL Rating | Package Marking [1] |
|-------------|--|---------------|------------|---------------------|
| HMC789ST89E | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL1 [2]   | H789<br>XXXX        |

<sup>[1] 4-</sup>Digit lot number XXXX

[2] Max peak reflow temperature of 260 °C





## InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

### **Pin Descriptions**

| Pin Number | Function | Description   | Interface Schematic |
|------------|----------|---|---------------------|
| 1          | RFIN     | This pin is DC coupled. Off chip matching components are required. See Application Circuit herein.                        | RFIN O——— RFOUT     |
| 3          | RFOUT    | RF output and DC Bias input for the amplifier. Off chip matching components are required. See Application Circuit herein. |                     |
| 2, 4       | GND      | These pins & package bottom must be connected to RF/DC ground.  | ○ GND<br>=          |

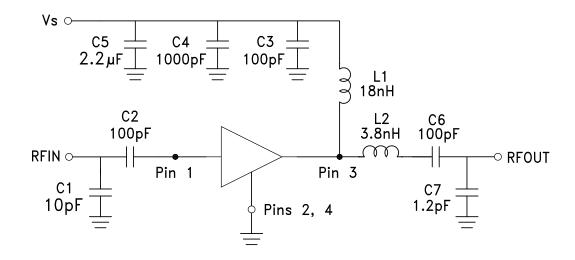




# InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

### 900 MHz Application Circuit

This circuit was used to specify the performance for 810-960 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



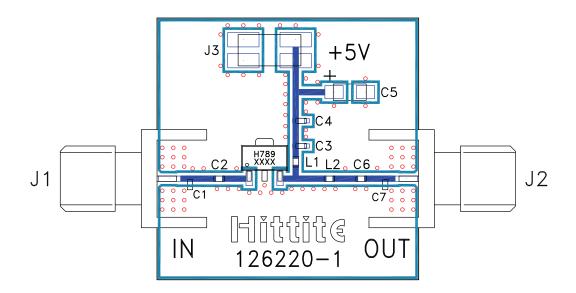
| Recommended Component Values |         |  |
|------------------------------|---------|--|
| C1                           | 10 pF   |  |
| C2                           | 100 pF  |  |
| C3                           | 100 pF  |  |
| C4                           | 1000 pF |  |
| C5                           | 2.2 μF  |  |
| C6                           | 100 pF  |  |
| C7                           | 1.2 pF  |  |
| L1                           | 18 nH   |  |
| L2                           | 3.8 nH  |  |





## InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

#### 900 MHz Evaluation PCB



#### List of Materials for 900 MHz Evaluation PCB 126222 [1]

| Item    | Description                  |
|---------|------------------------------|
| J1 - J2 | PCB Mount SMA Connector      |
| J3      | 2 mm DC Header               |
| C1      | 10 pF Capacitor, 0402 Pkg.   |
| C2      | 100 pF Capacitor, 0402 Pkg.  |
| C3      | 100 pF Capacitor, 0402 Pkg.  |
| C4      | 1000 pF Capacitor, 0402 Pkg. |
| C5      | 2.2 µF Capacitor, Tantalum   |
| C6      | 100 pF Capacitor, 0402 Pkg.  |
| C7      | 1.2 pF Capacitor, 0402 Pkg.  |
| L1      | 18 nH Inductor, 0402 Pkg.    |
| L2      | 3.8 nH Inductor, 0402 Pkg.   |
| U1      | HMC789ST89E Linear Amplifier |
| PCB [2] | 126220 Evaluation PCB        |

<sup>[1]</sup> Reference this number when ordering complete evaluation PCB

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

<sup>[2]</sup> Circuit Board Material: FR4

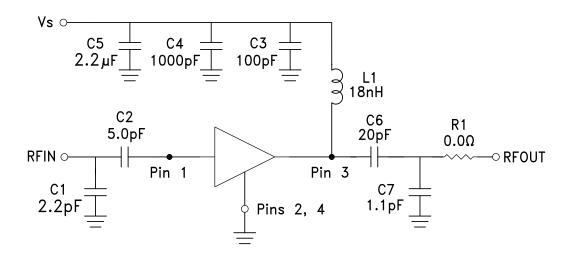




# InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

### 1900 MHz Application Circuit

This circuit was used to specify the performance for 1710-1990 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



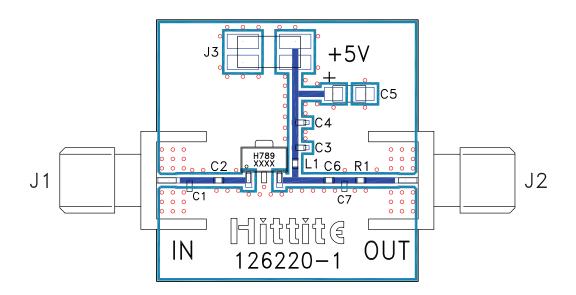
| Recommended Component Values |         |  |
|------------------------------|---------|--|
| C1                           | 2.2 pF  |  |
| C2                           | 5.0 pF  |  |
| C3                           | 100 pF  |  |
| C4                           | 1000 pF |  |
| C5                           | 2.2 μF  |  |
| C6                           | 20 pF   |  |
| C7                           | 1.1 pF  |  |
| L1                           | 20 nH   |  |
| R1                           | 0.0 Ohm |  |





## InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

#### 1900 MHz Evaluation PCB



#### List of Materials for 1900 MHz Evaluation PCB 126223 [1]

| Item    | Description                  |
|---------|------------------------------|
| J1 - J2 | PCB Mount SMA Connector      |
| J3      | 2 mm DC Header               |
| C1      | 2.2 pF Capacitor, 0402 Pkg.  |
| C2      | 5.0 pF Capacitor, 0402 Pkg.  |
| C3      | 100 pF Capacitor, 0402 Pkg.  |
| C4      | 1000 pF Capacitor, 0402 Pkg. |
| C5      | 2.2 µF Capacitor, Tantalum   |
| C6      | 20 pF Capacitor, 0402 Pkg.   |
| C7      | 1.1 pF Capacitor, 0402 Pkg.  |
| L1      | 18 nH Inductor, 0402 Pkg.    |
| R1      | 0.0 Ohm Resistor, 0402 Pkg.  |
| U1      | HMC789ST89E Linear Amplifier |
| PCB [2] | 126220 Evaluation PCB        |

<sup>[1]</sup> Reference this number when ordering complete evaluation PCB

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

<sup>[2]</sup> Circuit Board Material: FR4

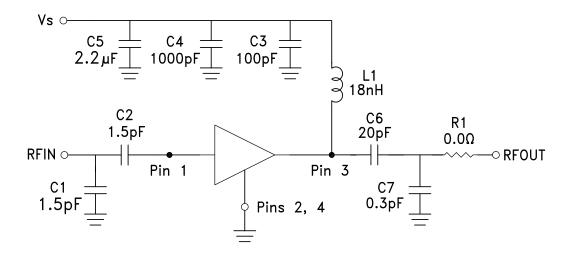




# InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

### 2600 MHz Application Circuit

This circuit was used to specify the performance for 2420-2700 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



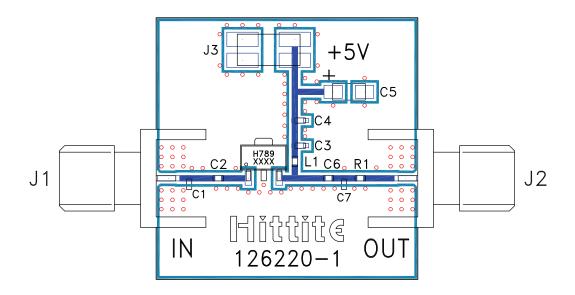
| Recommended Component Values |         |  |
|------------------------------|---------|--|
| C1                           | 1.5 pF  |  |
| C2                           | 1.5 pF  |  |
| C3                           | 100 pF  |  |
| C4                           | 1000 pF |  |
| C5                           | 2.2 μF  |  |
| C6                           | 20 pF   |  |
| C7                           | 0.3 pF  |  |
| L1                           | 18 nH   |  |
| L2                           | 12 nH   |  |
| R1                           | 0.0 Ohm |  |





## InGaP HBT GAIN BLOCK MMIC AMPLIFIER, 0.7 -2.8 GHz

#### 2600 MHz Evaluation PCB



### List of Materials for 2600 MHz Evaluation PCB 125682 [1]

| Item    | Description                  |
|---------|------------------------------|
| J1 - J2 | PCB Mount SMA Connector      |
| J3      | 2 mm DC Header               |
| C1      | 1.5 pF Capacitor, 0402 Pkg.  |
| C2      | 1.5 pF Capacitor, 0402 Pkg.  |
| C3      | 100 pF Capacitor, 0402 Pkg.  |
| C4      | 1000 pF Capacitor, 0402 Pkg. |
| C5      | 2.2 μF Capacitor, Tantalum   |
| C6      | 20 pF Capacitor, 0402 Pkg.   |
| C7      | 0.3 pF Capacitor, 0402 Pkg.  |
| L1      | 18 nH Inductor, 0402 Pkg.    |
| R1      | 0.0 Ohm Resistor, 0402 Pkg.  |
| U1      | HMC789ST89E Linear Amplifier |
| PCB [2] | 125220 Evaluation PCB        |

<sup>[1]</sup> Reference this number when ordering complete evaluation PCB

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

<sup>[2]</sup> Circuit Board Material: FR4

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MAAM-009633-001SMB MASW-000936-001SMB 107712-HMC369LP3 107780-HMC322ALP4 SP000416870 EV1HMC470ALP3
EV1HMC520ALC4 EV1HMC244AG16 MAX2614EVKIT# 124694-HMC742ALP5 SC20ASATEA-8GB-STD MAX2837EVKIT+
MAX2612EVKIT# MAX2692EVKIT# EV1HMC629ALP4E SKY12343-364LF-EVB 108703-HMC452QS16G EV1HMC863ALC4 119197HMC658LP2 EV1HMC647ALP6 ADL5725-EVALZ 106815-HMC441LM1 EV1HMC1018ALP4 UXN14M9PE MAX2016EVKIT
EV1HMC939ALP4 MAX2410EVKIT MAX2204EVKIT+ EV1HMC8073LP3D SIMSA868-DKL SIMSA868C-DKL SKY65806-636EK1
SKY68020-11EK1 SKY67159-396EK1 SKY66181-11-EK1 SKY65804-696EK1 SKY13396-397LF-EVB